

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L25	32	primary adj grain adj (boundary boundaries)	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 17:25
L26	913	(438/166).CCLS.	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 17:29
L27	33	l26 and SLS	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 17:29
L28	32	l27 not l25	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 17:57
L29	1124	(315/169.1).CCLS.	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 17:57
L30	1825	(315/169.3).CCLS.	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 17:58
S99	1705	(257/72).CCLS.	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S100	326	(257/64).CCLS.	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S101	198	(257/75).CCLS.	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S102	379	S99 and (TFT thin adj film adj transistor) and grain	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S103	202	S99 and flat adj panel adj display	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S104	194	S103 and (TFT thin adj film)	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S105	68	S101 and (display LED light-emitting light adj emitting) and (TFT thin adj film adj transistor)	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S106	64	S101 and grain adj (boundary boundaries)	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S107	24	S106 not S105	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S108	88	OLED and (polycrystalline poly adj Si recrystallized near2 (si silicon)) and grain adj (boundary boundaries) and (TFT thin adj film adj transistor)	US:PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41

S110	34	(jae adj bon near3 koo).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S111	42	(ji adj yong near3 park).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S112	27	S111 not S110	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S113	10	(hye adj dong near3 kim).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S114	8	(ul adj ho near3 lee).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S115	74	S104 and (driver driving) near3 (TFT transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S116	105	S100 and (TFT thin adj film adj transistor) and grain adj2 (boundary boundaries)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S117	196	OLED and (polycrystalline poly adj Si recrystallized near2 (si: silicon)) and grain and (TFT thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S118	244	S99 and (TFT thin adj film adj transistor) and grain adj2 (boundary boundaries)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S119	221	S100 not (S116 S118)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S120	124	S102 not (S116 S118 S119 S106 S105 S108)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S121	244	S99 and (TFT thin adj film adj transistor) and grain adj2 (boundary boundaries)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S122	215	S118 not S116	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S123	221	S100 not (S116 S118)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S124	326	(257/64).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S125	1435	(257/66).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S126	199	S125 and display and (TFT thin adj film adj transistor) and grain adj (boundaries boundary)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41

S127	116	S126 not S118	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S128	314	(poly adj Si polysilicon polycrystalline recrystallized) near3 active and transistor and channel and grain adj (boundaries boundary) and display	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S129	225	S128 not (S118 S116 S104 S126 S117)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S130	59	S129 and (driver driving) near2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S131	166	S129 not S130	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 14:13
S132	2	("6456013").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S133	3	("2002102821").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S134	4	("2003025119").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S135	0	("20002102821").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 13:41
S136	314	(poly adj Si polysilicon polycrystalline polycrystallization polycrystallizing recrystallized) near3 active and transistor and channel and grain adj (boundaries boundary) and display	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 13:41
S137	766	(257/88).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 14:13
S138	82	S137 and (poly adj si polycrystalline polysilicon polycrystallization polycrystallizing)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 14:19
S139	1927	(driver driving) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polysilicon poly adj si polycrystallizing recrystalliz\$5) and channel	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 14:30
S140	846	(driver driving) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polysilicon poly adj si polycrystallizing recrystalliz\$5) and channel and grain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 14:31
S141	711	(driver driving) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polycrystallizing recrystalliz\$5) and channel and grain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 15:04
S142	23	(driver driving) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polycrystallizing recrystalliz\$5) and channel and grain and (OLE LE)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 14:32
S143	1410	(257/401).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 14:37

S144	36	S143 and TFT and display	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/09 14:37
S145	78	(driver driving) near2 (TFT transistor) and switching near2 (TFT transistor) and flat adj panel adj2 display and (polycrystalline polycrystallization polycrystallizing recrystalliz\$5) and channel and grain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 09:55
S146	912	(438/166).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/09 15:05
S147	2	("6770546").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 10:24
S148	531	(channel TFT transistor) near3 (direction orientation oriented) same grain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 10:25
S149	358	S148 and display	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 10:33
S150	42	S148 and flat adj panel	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 10:34
S151	713	(driver driving) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polycrystallizing recrystalliz\$5) and channel and grain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:33
S152	493	S151 and (light adj emitting EL OEL OLED LED)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 11:14
S153	195	S149 and (light adj emitting EL OEL OLED LED)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:35
S154	326	(257/64).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 11:56
S155	75	S154 and (light adj emitting EL OEL OLED LED)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:12
S156	328	(257/89).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 12:27
S157	2	("20030062845").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/03/10 12:27
S158	725	(driver driving current adj control) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polycrystallizing recrystalliz\$5) and channel and grain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:33
S159	415	(driver driving current adj control) near2 (TFT transistor) and switching near2 (TFT transistor) and display and (polycrystalline polycrystallization polycrystallizing recrystalliz\$5) and channel and grain adj (boundary boundaries)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:34
S160	257	S159 and (light adj emitting EL OEL OLED LED)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:35

S161	194	S160 not S153	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/03/10 12:35
S162	3	("6456013")URPN	USPAT	OR	ON	2005/03/10 12:48